
Assignment-2 Finite Difference Method

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Introduction

The purpose of this lab is to analyse the current and voltage through a semiconductor using the finite difference method. This lab will look at the effect that differences between finite difference method and the analytical solutions for the voltage in the semiconductor. It will also look at the effects that mesh size, obstacle size and conductivity of the obstacles has on the current through the semiconductor.

Part 1A

This section looks at the solution for the case where a voltage is applied to one side of the semiconductor, while the other side is grounded, and the top and bottom are left free. The figure below shows the voltage at each point in the mesh relative to ground for the test case. It can be seen that the voltage follows a line with a negative slope. This is because the top and bottom are not held at a value and are allowed to converge to a voltage. The voltage that they converge to is the difference between the voltages divided by the length of the semiconductor times the distance along the semiconductor plus the applied voltage. This comes from Gauss's law.

```
clear
clc
close all

dx =1;
dy=1;
nx = 78;
ny = 52;
V = zeros(ny,nx);
G = sparse(nx*ny,nx*ny);
V0=1;
BC= [1, nan, 0,nan];
B = zeros(1,nx*ny);
for p = 1:size(B,2)

    if (p== 1)
        if isnan(BC(1))

            else
```

```
        B(p)=BC(1);
    end
elseif (p == nx)
    if isnan(BC(3))

        else
            B(p)=BC(3);
        end
elseif (p == (1+(ny-1)*nx))
    if isnan(BC(1))

        else
            B(p)=BC(1);
        end
elseif(p == nx*ny)
    if isnan(BC(3))

        else
            B(p)=BC(3);
        end
elseif(mod(p,nx)==0)
    if isnan(BC(3))

        else
            B(p)=BC(3);
        end
elseif(mod(p-1,nx)==0)
    if isnan(BC(1))

        else
            B(p) = BC(1);
        end
elseif(1<p&p<nx)
    if isnan(BC(4))

        else
            B(p) =BC(4);
        end
elseif((1+(ny-1)*nx)<p&p<nx*ny)
    if isnan(BC(2))

        else
            B(p) =BC(2);
        end
    else
end

end

for p = 1:ny
    for m = 1:nx
        n = m+(p-1)*nx;
        nxm = (m-1)+(p-1)*nx;
```

```
nxp = (m+1)+(p-1)*nx;
nym = (m)+(p-2)*nx;
nyp = m+(p)*nx;
nxm2 = (m-2)+(p-1)*nx;
nyp2=(m+2)+(p-1)*nx;
nym2 = (m)+(p-3)*nx;
nyp2 = m+(p+1)*nx;
nyp3 = (m+3)+(p-1)*nx;
nxm3 = (m-3)+(p-1)*nx;

if (n == 1)
    if (isnan(BC(1)))
        G(n,n)=-3/(2*dy)+2/(dx^3);
        G(n,nyp) =4/(2*dy);
        G(n,nyp2) =1/(2*dy);
        G(n,nxp)=-5/(dx^3);
        G(n,nxp2) =4/(dx^3);
        G(n,nxp3) =-1/(dx^3);
    else
        G(n,n)=1;
    end
elseif (n == nx)
    if (isnan(BC(3)))
        G(n,n)=3/(2*dx)+2/(dx^3);
        G(n,nym) =-4/(2*dx);
        G(n,nym2) =1/(2*dx);
        G(n,nxm)=-5/(dx^3);
        G(n,nxm2) =4/(dx^3);
        G(n,nxm3) =-1/(dx^3);
    else
        G(n,n)=1;
    end
elseif(n == (1+(ny-1)*nx))
    if (isnan(BC(1)))
        G(n,n)=3/(2*dy)+2/(dx^3);
        G(n,nyp) =-4/(2*dy);
        G(n,nyp2) =1/(2*dy);
        G(n,nxp)=-5/(dx^3);
        G(n,nxp2) =4/(dx^3);
        G(n,nxp3) =-1/(dx^3);
    else
        G(n,n)=1;
    end
elseif(n == nx*ny)
    if (isnan(BC(3)))
        G(n,n)=3/(2*dy)+2/(dx^3);
        G(n,nyp) =-4/(2*dy);
        G(n,nyp2) =1/(2*dy);
        G(n,nxm)=-5/(dx^3);
        G(n,nxm2) =4/(dx^3);
        G(n,nxm3) =-1/(dx^3);
```

```
else
    G(n,n)=1;

end
elseif(mod(n,nx)==0)
    if (isnan(BC(3)))
        G(n,n)=2/(dx^3);
        G(n,nym) =1/(2*dy);
        G(n,nyp) =1/(2*dy);
        G(n,nxm)=-5/(dx^3);
        G(n,nxm2) =4/(dx^3);
        G(n,nxm3) =-1/(dx^3);
    else
        G(n,n)=1;
    end
elseif(mod(n-1,nx)==0)
    if (isnan(BC(1)))
        G(n,n)=2/(dx^3);
        G(n,nym) =1/(2*dy);
        G(n,nyp) =1/(2*dy);
        G(n,nxp)=-5/(dx^3);
        G(n,nxp2) =4/(dx^3);
        G(n,nxp3) =-1/(dx^3);
    else
        G(n,n)=1;
    end
elseif (1<n&n<nx)
    if (isnan(BC(4)))
        G(n,n)=-3/(2*dy)-2/(dx^2);
        G(n,nyp) =4/(2*dy);
        G(n,nyp2) =-1/(2*dy);
        G(n,nxp) = 1/(dx^2);
        G(n,nxm) = 1/(dx^2);
    else
        G(n,n)=1;
    end
elseif ((1+(ny-1)*nx)<n&n<nx*ny)
    if (isnan(BC(2)))
        G(n,n)=3/(2*dy)-2/(dx^2);

        G(n,nym)=-4/(2*dy);
        G(n,nym2) =1/(2*dy);
        G(n,nxp) = 1/(dx^2);
        G(n,nxm) = 1/(dx^2);
    else
        G(n,n)=1;
    end
else
    G(n,n)=-4/(dx^2);
```

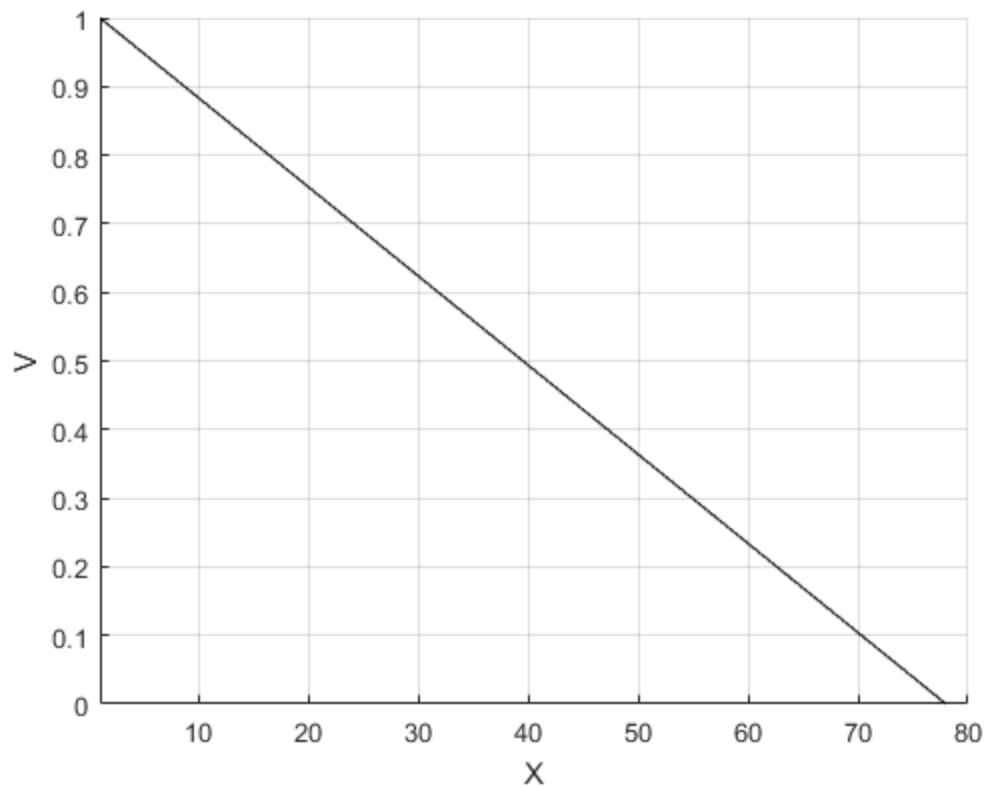
```
G(n,nxp) = 1/(dx^2);
G(n,nxm) = 1/(dx^2);
G(n,nym) = 1/(dx^2);
G(n,nyp) = 1/(dx^2);

    end

end

end
%figure('name', 'Matrix')
%spy(G)

V= G\B';
for p = 1:ny
    for m = 1:nx
        n = m+(p-1)*nx;
        Vout(p,m) =V(n);
    end
end
figure
surf(Vout)
xlim([1 80])
xlabel('X')
ylabel('Y')
zlabel('V')
view(0, 0)
```



Part 1B

This section looks at the difference between the numerical and analytical solution for the case where a voltage is applied across the sides of the semiconductor and the top and bottom are held at zero. The plot below shows the result for the numerical solution for the problem it can be seen from this that the boundary conditions are clearly defined. This is because the boundary voltages are well defined by the boundary conditions. The code segment below was used to generate the surface seen in the figure below.

```
clear
dx =1;
dy=1;
nx = 78;
ny = 52;
V = zeros(ny,nx);
G = sparse(nx*ny,nx*ny);
V0=1;
BC= [1, 0, 1,0];
B = zeros(1,nx*ny);
for p = 1:size(B,2)

    if (p== 1)
        if isnan(BC(1))

        else
            B(p)=BC(1);
        end
    end
end
```

```
elseif (p == nx)
    if isnan(BC(3))

        else
            B(p)=BC(3);
        end
    elseif (p == (1+(ny-1)*nx))
        if isnan(BC(1))

            else
                B(p)=BC(1);
            end
        elseif(p == nx*ny)
            if isnan(BC(3))

                else
                    B(p)=BC(3);
                end
            elseif(mod(p,nx)==0)
                if isnan(BC(3))

                    else
                        B(p)=BC(3);
                    end
                elseif(mod(p-1,nx)==0)
                    if isnan(BC(1))

                        else
                            B(p) = BC(1);
                        end
                    elseif(1<p&p<nx)
                        if isnan(BC(4))

                            else
                                B(p) =BC(4);
                            end
                        elseif((1+(ny-1)*nx)<p&p<nx*ny)
                            if isnan(BC(2))

                                else
                                    B(p) =BC(2);
                                end
                            else
                                end

end

end

for p = 1:ny
    for m = 1:nx
        n = m+(p-1)*nx;
        nxm = (m-1)+(p-1)*nx;
        nxp = (m+1)+(p-1)*nx;
        nym = (m)+(p-2)*nx;
```

```
nyp = m+(p)*nx;
nxm2 = (m-2)+(p-1)*nx;
nyp2=(m+2)+(p-1)*nx;
nym2 = (m)+(p-3)*nx;
nyp2 = m+(p+1)*nx;
nyp3 = (m+3)+(p-1)*nx;
nxm3 = (m-3)+(p-1)*nx;

if (n == 1)
    if (isnan(BC(1)))
        G(n,n)=-3/(2*dy)+2/(dx^3);
        G(n,nyp) =4/(2*dy);
        G(n,nyp2) =1/(2*dy);
        G(n,nxp)=-5/(dx^3);
        G(n,nxp2) =4/(dx^3);
        G(n,nxp3) =-1/(dx^3);
    else
        G(n,n)=1;
    end
elseif (n == nx)
    if (isnan(BC(3)))
        G(n,n)=3/(2*dx)+2/(dx^3);
        G(n,nym) =-4/(2*dx);
        G(n,nym2) =1/(2*dx);
        G(n,nxm)=-5/(dx^3);
        G(n,nxm2) =4/(dx^3);
        G(n,nxm3) =-1/(dx^3);
    else
        G(n,n)=1;
    end
elseif(n == (1+(ny-1)*nx))
    if (isnan(BC(1)))
        G(n,n)=3/(2*dy)+2/(dx^3);
        G(n,nyp) =-4/(2*dy);
        G(n,nyp2) =1/(2*dy);
        G(n,nxp)=-5/(dx^3);
        G(n,nxp2) =4/(dx^3);
        G(n,nxp3) =-1/(dx^3);
    else
        G(n,n)=1;
    end
elseif(n == nx*ny)
    if (isnan(BC(3)))
        G(n,n)=3/(2*dy)+2/(dx^3);
        G(n,nyp) =-4/(2*dy);
        G(n,nyp2) =1/(2*dy);
        G(n,nxm)=-5/(dx^3);
        G(n,nxm2) =4/(dx^3);
        G(n,nxm3) =-1/(dx^3);
    else
        G(n,n)=1;
    end
end
```



```
end
elseif(mod(n,nx)==0)
    if (isnan(BC(3)))
        G(n,n)=2/(dx^3);
        G(n,nym) =1/(2*dy);
        G(n,nyp) =1/(2*dy);
        G(n,nxm)=-5/(dx^3);
        G(n,nxm2) =4/(dx^3);
        G(n,nxm3) =-1/(dx^3);
    else
        G(n,n)=1;
    end
elseif(mod(n-1,nx)==0)
    if (isnan(BC(1)))
        G(n,n)=2/(dx^3);
        G(n,nym) =1/(2*dy);
        G(n,nyp) =1/(2*dy);
        G(n,nxp)=-5/(dx^3);
        G(n,nxp2) =4/(dx^3);
        G(n,nxp3) =-1/(dx^3);
    else
        G(n,n)=1;
    end
elseif (1<n&n<nx)
    if (isnan(BC(4)))
        G(n,n)=-3/(2*dy)-2/(dx^2);
        G(n,nyp) =4/(2*dy);
        G(n,nyp2) =-1/(2*dy);
        G(n,nxp) = 1/(dx^2);
        G(n,nxm) = 1/(dx^2);
    else
        G(n,n)=1;
    end
elseif ((1+(ny-1)*nx)<n&n<nx*ny)
    if (isnan(BC(2)))
        G(n,n)=3/(2*dy)-2/(dx^2);

        G(n,nym)=-4/(2*dy);
        G(n,nym2) =1/(2*dy);
        G(n,nxp) = 1/(dx^2);
        G(n,nxm) = 1/(dx^2);
    else
        G(n,n)=1;
    end
else
    G(n,n)=-4/(dx^2);
    G(n,nxp) = 1/(dx^2);
    G(n,nxm) = 1/(dx^2);
```

```
G(n,nym) = 1/(dx^2);
G(n,nyp) = 1/(dx^2);

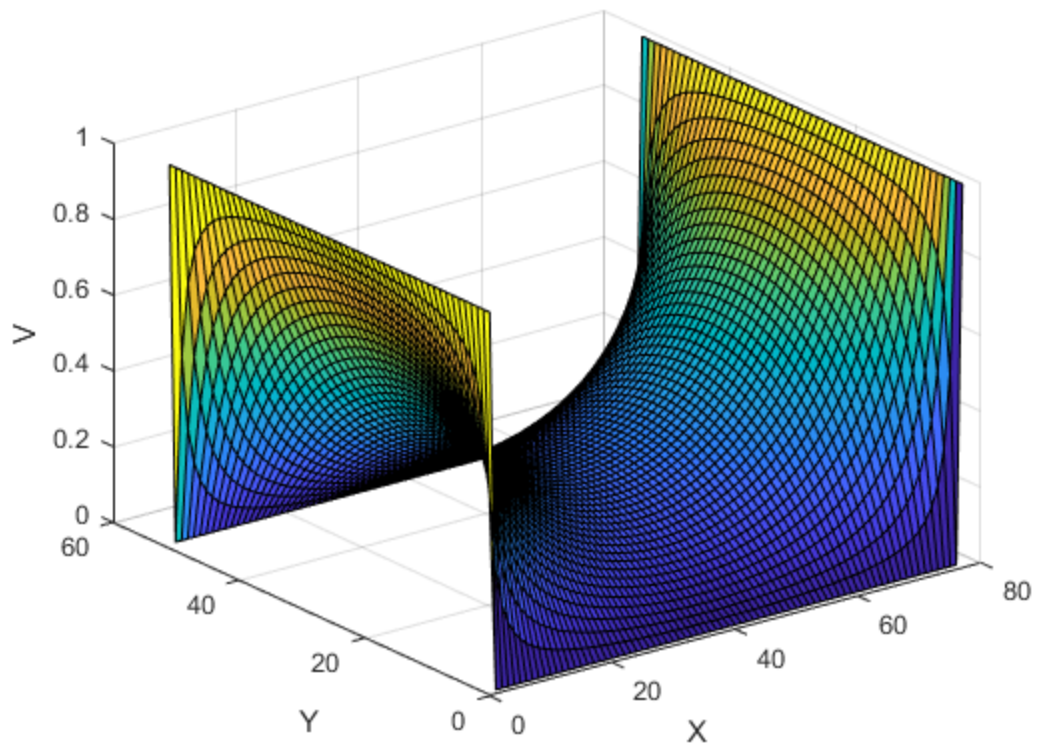
end

end

end
%figure('name', 'Matrix')
%spy(G)

V= G\B';
for p = 1:ny
    for m = 1:nx
        n = m+(p-1)*nx;
        Vout(p,m) =V(n);
    end
end
figure
surf(Vout)
xlabel('X')
ylabel('Y')
zlabel('V')

x = 0:1:nx-1;
y = 0:1:(ny-1);
[X,Y]= meshgrid(x,y);
V2 = zeros (size(X));
```

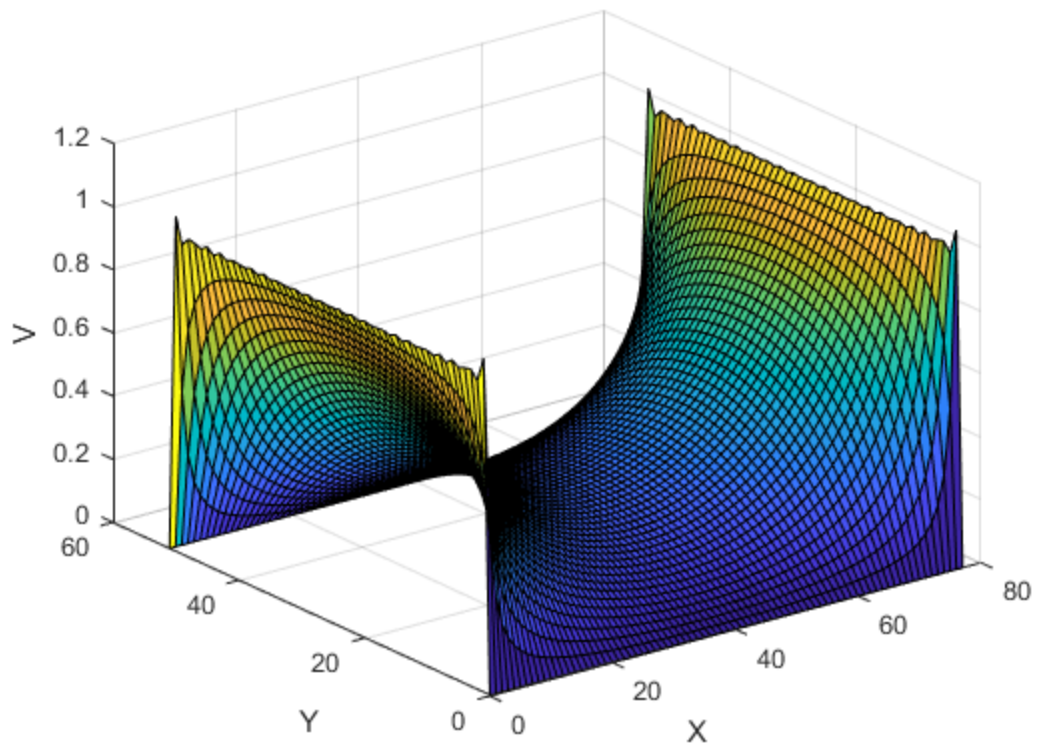


The plot below was generated using the following code. It can be seen from the plot that the value of the voltage at the side of the semiconductor does not converge to a singular value. Instead it oscillates about the applied voltage. This is due to the finite approximation of used to generate the solution. Increasing the number of approximations will result in the boundaries being more well defined.

```
for u = 1:2:160

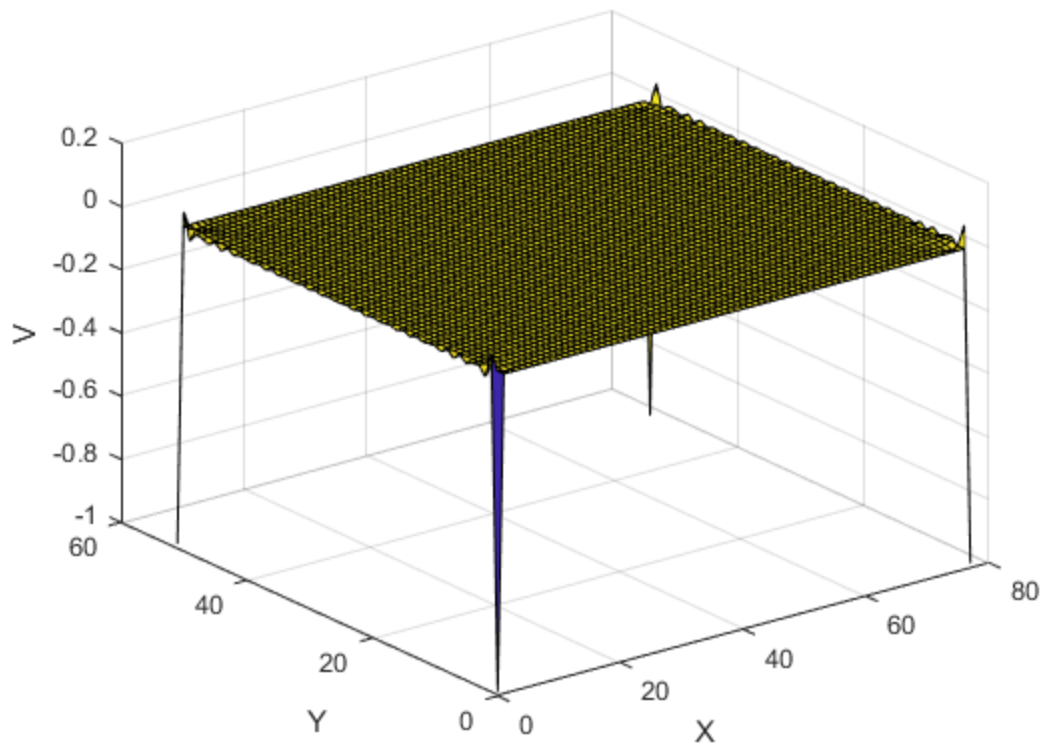
    A= ((cosh(u*pi.*(X-(nx-1)/2)./(ny-1)))./((cosh(u*pi* ((nx-1)/2)/
(ny-1)))));
    C=sin((u*pi.*Y)./(ny-1));
    V2 = V2+ (1/u)*A.*C;

end
V2 =V2*(4*pi);
figure
surf(X,Y,V2)
xlabel('X')
ylabel('Y')
zlabel('V')
```



The plot below shows the difference between the numerical and analytical solutions for the problem. From this figure it can be seen that the largest difference appears at the corners of the semiconductors. This is because the corners of the semiconductor require more approximations to generate the correct answer.

```
diff = V2 - Vout;  
figure  
surf(diff)  
xlabel('X')  
ylabel('Y')  
zlabel('V')
```



Part 2A

Using the following code this section looks at the analysis of the current through a semiconductor composed of a conductive region with two nonconductive blocks placed at the center of the semiconductor. To analyse the current through the semiconductor a potential of one was applied across the material.

```
sig = 1;  
sigbox = 10e-2;  
  
box1pos= [29,20];  
box2pos= [29,ny];  
box1dim= [20,20];  
box2dim= [20,20];  
  
dx2 =1;  
dy2=1;  
nx2 = 78;  
ny2 = 52;  
V3 = zeros(ny,nx);  
G2= sparse(nx*ny,nx*ny);  
V02=1;  
BC2= [1, nan, 0,nan];  
B2 = zeros(1,nx*ny);  
cond = zeros (ny,nx);  
% sets up conduction map
```

```
for p = 1:ny2
    for m = 1:nx2

        if ((m >= box1pos(1) & m <= box1pos(1) + box1dim(1)) & p
<= box1pos(2) & p >= box1pos(2) - box1dim(2)) | ((m >= box2pos(1) & m
<= box2pos(1) + box2dim(1)) & p <= box2pos(2) & p >= box2pos(2) - box2dim(2))
            cond(p,m) = sigbox;
        else
            cond(p,m) = sig;
        end
    end
end
```

```
for p = 1:size(B2,2)

    if (p == 1)
        if isnan(BC2(1))

            else
                B2(p) = BC2(1);
            end
        elseif (p == nx)
            if isnan(BC2(3))

                else
                    B2(p) = BC2(3);
                end
            elseif (p == (1+(ny-1)*nx))
                if isnan(BC2(1))

                    else
                        B2(p) = BC2(1);
                    end
                elseif (p == nx*ny)
                    if isnan(BC2(3))

                        else
                            B2(p) = BC2(3);
                        end
                    elseif (mod(p,nx) == 0)
                        if isnan(BC2(3))

                            else
                                B2(p) = BC2(3);
                            end
                        elseif (mod(p-1,nx) == 0)
                            if isnan(BC2(1))

                                else
                                    B2(p) = BC2(1);
                                end
                            end
                        end
                    end
```

```
elseif(1<p&p<nx)
    if isnan(BC2(4))

        else
            B2(p) =BC2(4);
        end
    elseif((1+(ny-1)*nx)<p&p<nx*ny)
        if isnan(BC2(2))

            else
                B2(p) =BC2(2);
            end
        else

            end

end

end

for p = 1:ny2
    for m = 1:nx2
        n = m+(p-1)*nx2;
        nxm = (m-1)+(p-1)*nx2;
        nxp = (m+1)+(p-1)*nx2;
        nym = (m)+(p-2)*nx2;
        nyp = m+(p)*nx2;
        nxm2 = (m-2)+(p-1)*nx2;
        nxp2=(m+2)+(p-1)*nx2;
        nym2 = (m)+(p-3)*nx2;
        nyp2 = m+(p+1)*nx2;
        nxp3 = (m+3)+(p-1)*nx2;
        nxm3 = (m-3)+(p-1)*nx2;

        if m == 1
            G2(n,:) =0;
            G2(n,n)=1;

        elseif m==nx2
            G2(n,:) =0;
            G2(n,n)=1;

        elseif p ==1

            ryp = (cond(p,m)+cond(p+1,m))/2;
            rxp = (cond(p,m)+cond(p,m+1))/2;
            rxm = (cond(p,m)+cond(p,m-1))/2;

            G2(n,n) = -(ryp+rxp+rxm);
            G2(n,nyp)= ryp;
            G2(n,nxm)= rxm;
            G2(n,nxp) = rxp;

        elseif p==ny2
            rym = (cond(p,m)+cond(p-1,m))/2;
            rxp = (cond(p,m)+cond(p,m+1))/2;
```

```
rxm = (cond(p,m)+cond(p,m-1))/2;

G2(n,n) = -(rym+rxp+rxm);
G2(n,nym)= rym;
G2(n,nxm)= rxm;
G2(n,nxp) = rxp;
else
ryp = (cond(p,m)+cond(p+1,m))/2;
rym = (cond(p,m)+cond(p-1,m))/2;
rxp = (cond(p,m)+cond(p,m+1))/2;
rxm = (cond(p,m)+cond(p,m-1))/2;

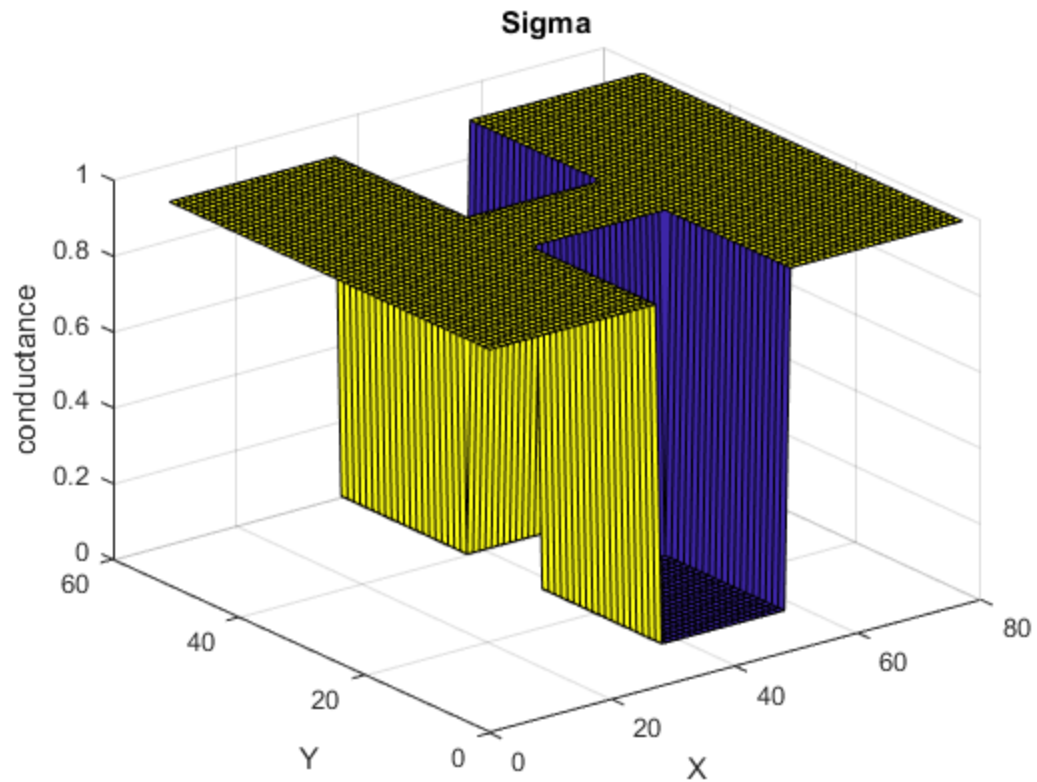
G2(n,n) = -(ryp+rym+rxp+rxm);
G2(n,nyp)= ryp;
G2(n,nym)= rym;
G2(n,nxm)= rxm;
G2(n,nxp) = rxp;
end

end
end
%figure('name', 'Matrix')
%spy(G2)

V3 = G2\B2';
Vout2 = zeros(ny, nx);
for p = 1:ny
    for m = 1:nx
        n = m+(p-1)*nx;
        Vout2(p,m) =V3(n);
    end
end
end
```

The plot below shows the conductivity map for the semiconductor. The regions of the map that are blue represent the regions that are inside the low conductivity boxes.

```
figure
surf(cond)
title('Sigma')
xlabel('X')
ylabel('Y')
zlabel('conductance')
```

The following plot shows the voltage at each point of the mesh. From this plot it can be seen that the voltage tries to remain linear through the bottleneck but is distorted by the blocks. This is because there is a large voltage drop across the high resistanc blocks that forces the current to flow through the bottleneck causing decrease in the voltage dropped across this region due to the conservation of energy.

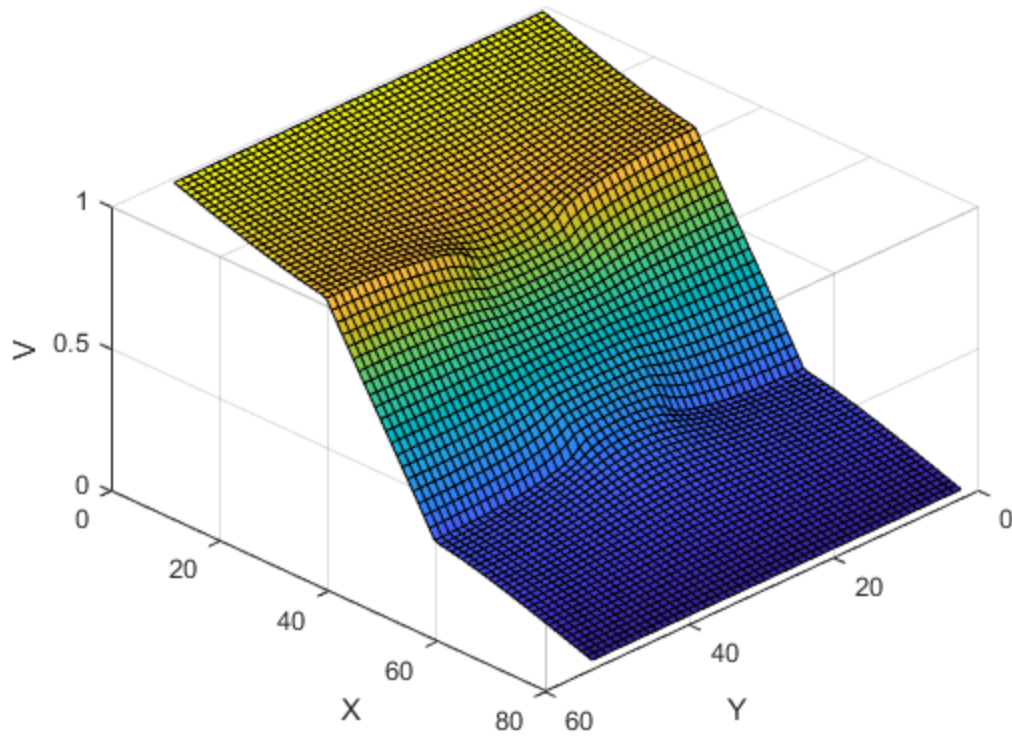
```
figure
title('Voltage')
surf(Vout2)
xlabel('X')
ylabel('Y')
zlabel('V')
view(-45, -45)

Ex= size (Vout2);
Ey = size (Vout2);
for p = 1:ny
    for m = 1:nx

        if (m==1)
            Ex(p,m) = Vout2(p,m+1)-Vout2(p,m);
        elseif m == nx
            Ex(p,m) = Vout2(p,m)-Vout2(p,m-1);
        else
            Ex(p,m) = (Vout2(p,m+1)-Vout2(p,m-1))/2;
        end
    end
end
```

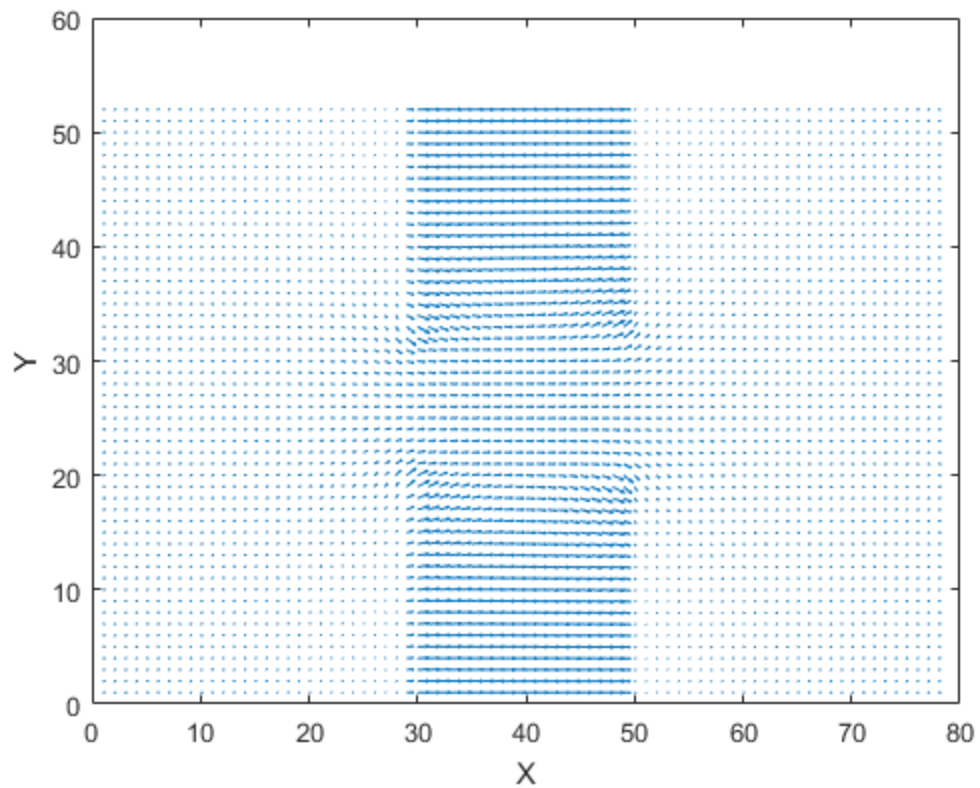
```
        if (p==1)
            Ey(p,m) = Vout2(p+1,m)-Vout2(p,m);
        elseif p == ny
            Ey(p,m) = Vout2(p,m)-Vout2(p-1,m);
        else
            Ey(p,m) = (Vout2(p+1,m)-Vout2(p-1,m))/2;
        end
    end
end
Ex = -Ex;
Ey = -Ey;

currentx = cond.*Ex;
currenty = cond.*Ey;
```



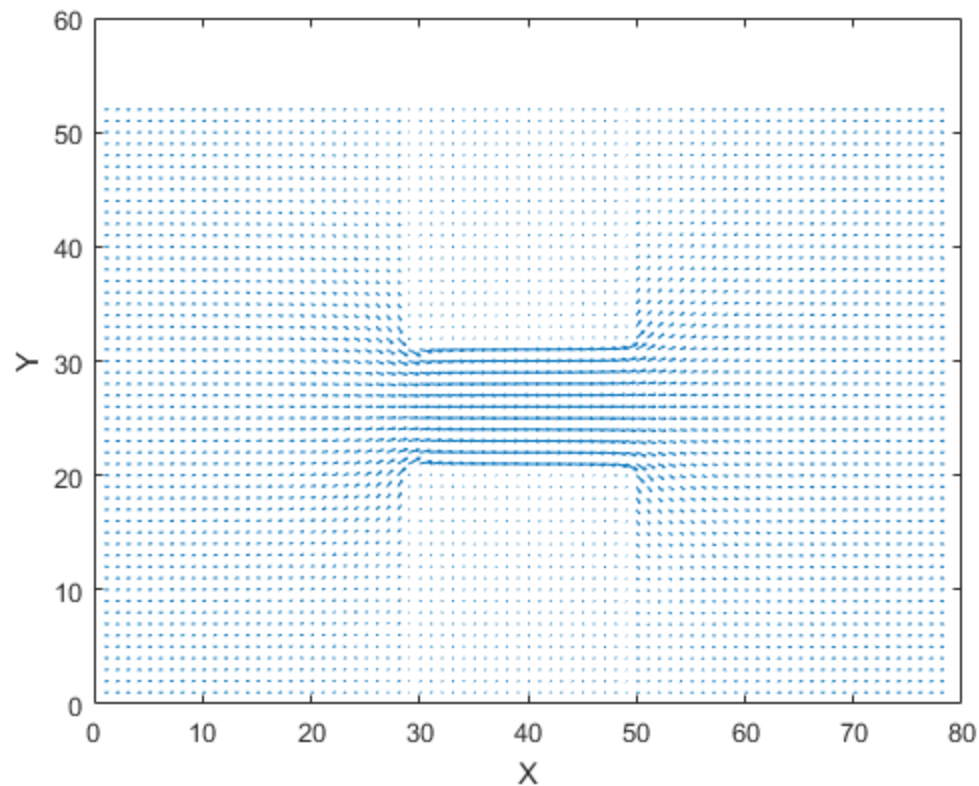
From the plot below it can be seen that the magnitude of the electric field increase in the high resistance blocks. This corresponds to the large voltage drop in these regions seen above.

```
figure
title('Electric Field')
quiver(Ex, Ey);
xlabel('X')
ylabel('Y')
```



As expected the following plot shows an increase in current through the bottleneck that accounts for the decrease in current through the high resistance blocks.

```
figure
title('Current')
quiver(currentx,currenty)
xlabel('X')
ylabel('Y')
```



Part 2B

The code below looks at the effect that mesh size has on the total current flowing through the semiconductor. To accomplish this the mesh size was incremented by the base mesh size to increase the resolution of the plot. The step size of each grid was also divided by the number of increments to maintain the scale of the semiconductor. From the plot below it can be seen that as the step size decrease the current converges to a value. This is because the accuracy of the simulation is dependent on the step size. It is also important to note that the increasing the step size increases the simulation time because the number of iterations needed increases.

```
for l = 1 : 5

    sig = 1;
    sigbox = 10e-2;

    dx2 = 1/l;
    dy2 = 1/l;
    nx2 = 78*l;
    ny2 = 52*l;
    box1pos = [29*l, 20*l];
    box2pos = [29*l, ny2];
    box1dim = [20*l, 20*l];
    box2dim = [20*l, 20*l];
```

```
V3 = zeros(ny2,nx2);
G2= sparse(nx2*ny2,nx2*ny2);
V02=1;
BC2= [1, nan, 0,nan];
B2 = zeros(1,nx2*ny2);
cond = zeros (ny2,nx2);
% sets up conduction map

for p = 1:ny2
    for m = 1:nx2

        if ((m >=box1pos(1)&m <=box1pos(1)+box1dim(1))&p
<=box1pos(2)&p >=box1pos(2)-box1dim(2)) | ((m >=box2pos(1)&m
<=box2pos(1)+box2dim(1))&p <=box2pos(2)&p >=box2pos(2)-box2dim(2))
            cond(p,m) =sigbox;
        else
            cond(p,m) =sig;
        end
    end
end

for p = 1:size(B2,2)

    if (p== 1)
        if isnan(BC2(1))

            else
                B2(p)=BC2(1);
            end
        elseif (p == nx2)
            if isnan(BC2(3))

            else
                B2(p)=BC2(3);
            end
        elseif (p == (1+(ny2-1)*nx2))
            if isnan(BC2(1))

            else
                B2(p)=BC2(1);
            end
        elseif(p == nx2*ny2)
            if isnan(BC2(3))

            else
                B2(p)=BC2(3);
            end
        elseif(mod(p,nx2)==0)
            if isnan(BC2(3))

            else
                B2(p)=BC2(3);
            end
        end
    end
end
```

```
        end
    elseif(mod(p-1,nx2)==0)
        if isnan(BC2(1))

            else
                B2(p) = BC2(1);
            end
        elseif(1<p&p<nx2)
            if isnan(BC2(4))

                else
                    B2(p) =BC2(4);
                end
            elseif((1+(ny2-1)*nx2)<p&p<nx2*ny2)
                if isnan(BC2(2))

                    else
                        B2(p) =BC2(2);
                    end
                else

            end

        end

    end

for p = 1:ny2
    for m = 1:nx2
        n = m+(p-1)*nx2;
        nxm = (m-1)+(p-1)*nx2;
        nxp = (m+1)+(p-1)*nx2;
        nym = (m)+(p-2)*nx2;
        nyp = m+(p)*nx2;
        nxm2 = (m-2)+(p-1)*nx2;
        nxp2=(m+2)+(p-1)*nx2;
        nym2 = (m)+(p-3)*nx2;
        nyp2 = m+(p+1)*nx2;
        nxp3 = (m+3)+(p-1)*nx2;
        nxm3 = (m-3)+(p-1)*nx2;

        if m == 1
            G2(n,:) = 0;
            G2(n,n) = 1;

        elseif m==nx2
            G2(n,:) = 0;
            G2(n,n) = 1;

        elseif p == 1

            ryp = (cond(p,m)+cond(p+1,m))/(2);
            rxp = (cond(p,m)+cond(p,m+1))/(2);
            rxm = (cond(p,m)+cond(p,m-1))/(2);

            G2(n,n) = -(ryp+rxp+rxm);
```

```

G2(n,ny2)= ryp;
G2(n,nxm)= rxm;
G2(n,nxp) = rxp;

elseif p==ny2
    rym = (cond(p,m)+cond(p-1,m))/(2);
    rxp = (cond(p,m)+cond(p,m+1))/(2);
    rxm = (cond(p,m)+cond(p,m-1))/(2);

    G2(n,n) = -(rym+rxp+rxm);
    G2(n,ny2)= rym;
    G2(n,nxm)= rxm;
    G2(n,nxp) = rxp;
else
    ryp = (cond(p,m)+cond(p+1,m))/(2);
    rym = (cond(p,m)+cond(p-1,m))/(2);
    rxp = (cond(p,m)+cond(p,m+1))/(2);
    rxm = (cond(p,m)+cond(p,m-1))/(2);

    G2(n,n) = -(ryp+rym+rxp+rxm);
    G2(n,ny2)= ryp;
    G2(n,ny2)= rym;
    G2(n,nxm)= rxm;
    G2(n,nxp) = rxp;
end

end

end
%figure('name', 'Matrix')
%spy(G2)

V3 = G2\B2';
Vout2 = zeros(ny2, nx2);
for p = 1:ny2
    for m = 1:nx2
        n = m+(p-1)*nx2;
        Vout2(p,m) =V3(n);
    end
end

% figure
% surf(cond)
% xlabel('X')
% ylabel('Y')
% zlabel('conductance')
% figure
% surf(Vout2)
% xlabel('X')
% ylabel('Y')
% zlabel('V')
% view(-45, -45)

Ex= zeros(size (Vout2));
Ey = zeros(size (Vout2));

```

```

for p = 1:ny2
    for m = 1:nx2

        if (m==1)
            Ex(p,m) = (Vout2(p,m+1)-Vout2(p,m))/dx2;
        elseif m == nx2
            Ex(p,m) = (Vout2(p,m)-Vout2(p,m-1))/dx2;
        else
            Ex(p,m) = (Vout2(p,m+1)-Vout2(p,m-1))/(2*dx2);

        end
        if (p==1)
            Ey(p,m) = (Vout2(p+1,m)-Vout2(p,m))/dy2;
        elseif p == ny2
            Ey(p,m) = (Vout2(p,m)-Vout2(p-1,m))/dy2;
        else
            Ey(p,m) = (Vout2(p+1,m)-Vout2(p-1,m))/(2*dy2);

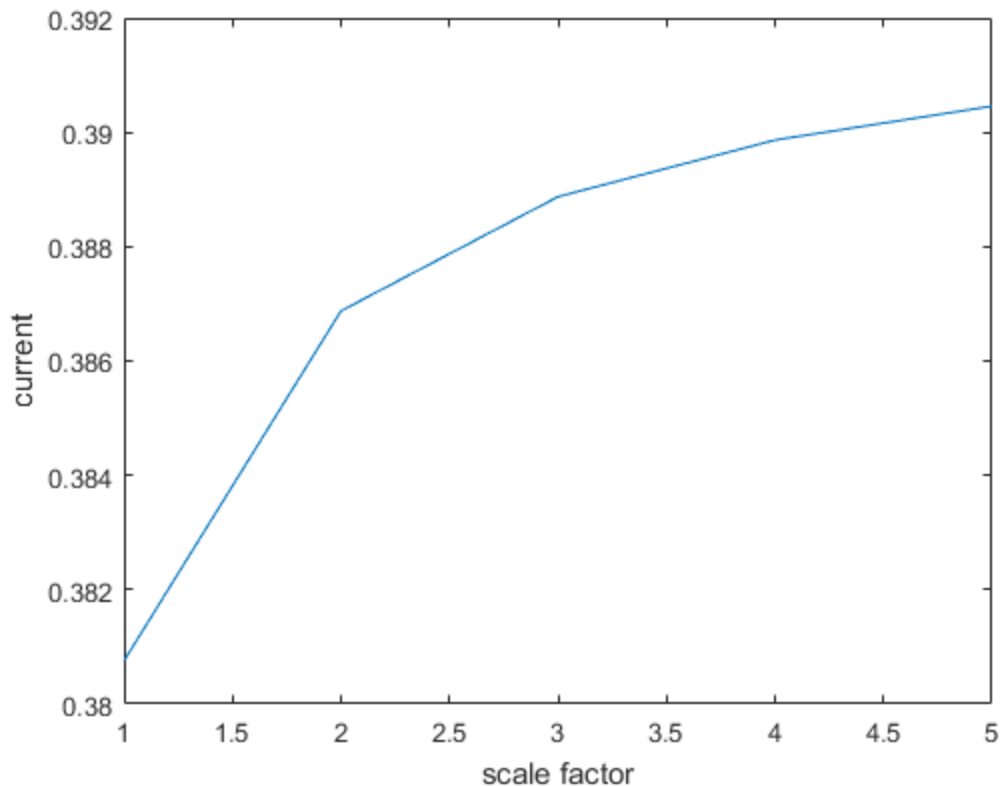
        end
    end
end
Ex = -Ex;
Ey = -Ey;

currentx = cond.*Ex.*dx2;
currenty = cond.*Ey.*dy2;

% figure
% quiver(Ex, Ey);
% xlabel('X')
% ylabel('Y')
%
%
% figure
% quiver(currentx,currenty)
% xlabel('X')
% ylabel('Y')

current(1) = mean(sum(sqrt(currentx.^2+ currenty.^2)));
end
figure
plot(linspace(1,5,5),current)
xlabel('scale factor')
ylabel('current')

```

Part 2C

This section looks at the effect that the size of the gap or conversly the size of the blocks has on the current through the semiconductor. To accomplish this the size of the blocks were itertavly increased and the total current through was recoded and plotted. from the plot below it can be seen that the current through the material decrease with the size of the high resistance regions. The current becomes remains steady once the high resistance regionds meets this is because the currnet nolonger has a low recistance path to follow and is forced to moved through the high resistance region.

```
for l =1 :30

sig = 1;
sigbox = 10e-2;

box1pos= [29,9+1];
box2pos= [29,ny];
box1dim= [20,9+1];
box2dim= [20,9+1];

dx2 =1;
dy2=1;
nx2 = 78;
ny2 = 52;
V3 = zeros(ny,nx);
G2= sparse(nx*ny,nx*ny);
```

```
V02=1;
BC2= [1, nan, 0,nan];
B2 = zeros(1,nx*ny);
cond = zeros (ny,nx);
% sets up conduction map

for p = 1:ny2
    for m = 1:nx2

        if ((m >=box1pos(1)&m <=box1pos(1)+box1dim(1))&p
<=box1pos(2)&p >=box1pos(2)-box1dim(2))|((m >=box2pos(1)&m
<=box2pos(1)+box2dim(1))&p <=box2pos(2)&p >=box2pos(2)-box2dim(2))
            cond(p,m) =sigbox;
        else
            cond(p,m) =sig;
        end
    end
end

for p = 1:size(B2,2)

    if (p== 1)
        if isnan(BC2(1))

            else
                B2(p)=BC2(1);
            end
        elseif (p == nx)
            if isnan(BC2(3))

            else
                B2(p)=BC2(3);
            end
        elseif (p == (1+(ny-1)*nx))
            if isnan(BC2(1))

            else
                B2(p)=BC2(1);
            end
        elseif(p == nx*ny)
            if isnan(BC2(3))

            else
                B2(p)=BC2(3);
            end
        elseif(mod(p,nx)==0)
            if isnan(BC2(3))

            else
                B2(p)=BC2(3);
            end
        elseif(mod(p-1,nx)==0)
```

```
        if isnan(BC2(1))

            else
                B2(p) = BC2(1);
            end
        elseif(1<p&p<nx)
            if isnan(BC2(4))

                else
                    B2(p) =BC2(4);
                end
            elseif((1+(ny-1)*nx)<p&p<nx*ny)
                if isnan(BC2(2))

                    else
                        B2(p) =BC2(2);
                    end
                else

            end

        end

    end

for p = 1:ny2
    for m = 1:nx2
        n = m+(p-1)*nx2;
        nxm = (m-1)+(p-1)*nx2;
        nxp = (m+1)+(p-1)*nx2;
        nym = (m)+(p-2)*nx2;
        nyp = m+(p)*nx2;
        nxm2 = (m-2)+(p-1)*nx2;
        nxp2=(m+2)+(p-1)*nx2;
        nym2 = (m)+(p-3)*nx2;
        nyp2 = m+(p+1)*nx2;
        nxp3 = (m+3)+(p-1)*nx2;
        nxm3 = (m-3)+(p-1)*nx2;

        if m == 1
            G2(n,:) = 0;
            G2(n,n) = 1;

        elseif m==nx2
            G2(n,:) = 0;
            G2(n,n) = 1;

        elseif p == 1

            ryp = (cond(p,m)+cond(p+1,m))/2;
            rxp = (cond(p,m)+cond(p,m+1))/2;
            rxm = (cond(p,m)+cond(p,m-1))/2;

            G2(n,n) = -(ryp+rxp+rxm);
            G2(n,nyp) = ryp;
            G2(n,nxm) = rxm;
```

```

        G2(n,nxp) = rxp;

elseif p==ny2
    rym = (cond(p,m)+cond(p-1,m))/2;
    rxp = (cond(p,m)+cond(p,m+1))/2;
    rxm = (cond(p,m)+cond(p,m-1))/2;

    G2(n,n) = -(rym+rxp+rxm);
    G2(n,nym)= rym;
    G2(n,nxm)= rxm;
    G2(n,nxp) = rxp;
else
    ryp = (cond(p,m)+cond(p+1,m))/2;
    rym = (cond(p,m)+cond(p-1,m))/2;
    rxp = (cond(p,m)+cond(p,m+1))/2;
    rxm = (cond(p,m)+cond(p,m-1))/2;

    G2(n,n) = -(ryp+rym+rxp+rxm);
    G2(n,nyp)= ryp;
    G2(n,nym)= rym;
    G2(n,nxm)= rxm;
    G2(n,nxp) = rxp;
end

end

end
%figure('name', 'Matrix')
%spy(G2)

V3 = G2\B2';
Vout2 = zeros(ny, nx);
for p = 1:ny
    for m = 1:nx
        n = m+(p-1)*nx;
        Vout2(p,m) =V3(n);
    end
end

% figure
% surf(cond)
% xlabel('X')
% ylabel('Y')
% zlabel('conductance')
% figure
% surf(Vout2)
% xlabel('X')
% ylabel('Y')
% zlabel('V')
% view(-45, -45)

Ex= size (Vout2);
Ey = size (Vout2);
for p = 1:ny
    for m = 1:nx

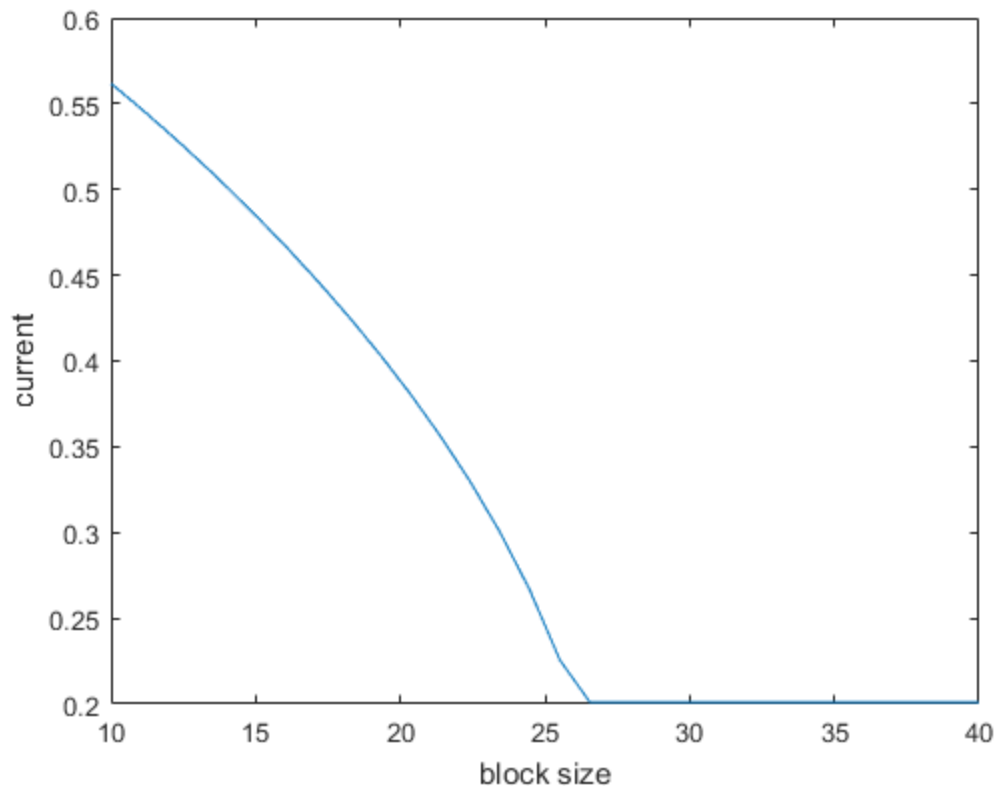
```

```
    if (m==1)
        Ex(p,m) = Vout2(p,m+1)-Vout2(p,m);
    elseif m == nx
        Ex(p,m) = Vout2(p,m)-Vout2(p,m-1);
    else
        Ex(p,m) = (Vout2(p,m+1)-Vout2(p,m-1))/2;
    end
    if (p==1)
        Ey(p,m) = Vout2(p+1,m)-Vout2(p,m);
    elseif p == ny
        Ey(p,m) = Vout2(p,m)-Vout2(p-1,m);
    else
        Ey(p,m) = (Vout2(p+1,m)-Vout2(p-1,m))/2;
    end
end
end
Ex = -Ex;
Ey = -Ey;

currentx = cond.*Ex;
currenty = cond.*Ey;

% figure
% quiver(Ex, Ey);
% xlabel('X')
% ylabel('Y')
%
%
% figure
% quiver(currentx,currenty)
% xlabel('X')
% ylabel('Y')

current(1) = mean(sum(sqrt(currentx.^2+ currenty.^2)));
end
figure
plot(linspace(10,40,30),current)
xlabel('block size')
ylabel('current')
```



Part 2D

This section looks at the current that flows through the material given a change in conductivity of the blocks. To analyse this a variety of conductances were iterated through and the resulting currents were stored. From the plot below it can be seen that the current through the semiconductor increases as the conductance increases. It can also be seen that the plot tails off as the "low resistance" material becomes more resistive than the "high resistive material". This is because parallel resistances approach the value of the lowest resistive branch as the resistance of other branches increases.

```
t =  
[1e-10,1,2,3,4,5,6,7,8,9,10,11,12,13,14,15,16,17,18,19,20,21,22,23,24,25,26,27,28  
for l =1 :101  
  
sig = 1;  
sigbox = t(l)*10e-2;  
  
box1pos= [29,20];  
box2pos= [29,ny];  
box1dim= [20,20];  
box2dim= [20,20];  
  
dx2 =1;  
dy2=1;  
nx2 = 78;  
ny2 = 52;
```

```
V3 = zeros(ny,nx);
G2= sparse(nx*ny,nx*ny);
V02=1;
BC2= [1, nan, 0,nan];
B2 = zeros(1,nx*ny);
cond = zeros (ny,nx);
% sets up conduction map

for p = 1:ny2
    for m = 1:nx2

        if ((m >=box1pos(1)&m <=box1pos(1)+box1dim(1))&p
<=box1pos(2)&p >=box1pos(2)-box1dim(2)) | ((m >=box2pos(1)&m
<=box2pos(1)+box2dim(1))&p <=box2pos(2)&p >=box2pos(2)-box2dim(2))
            cond(p,m) =sigbox;
        else
            cond(p,m) =sig;
        end
    end
end

for p = 1:size(B2,2)

    if (p== 1)
        if isnan(BC2(1))

            else
                B2(p)=BC2(1);
            end
        elseif (p == nx)
            if isnan(BC2(3))

                else
                    B2(p)=BC2(3);
                end
            elseif (p == (1+(ny-1)*nx))
                if isnan(BC2(1))

                    else
                        B2(p)=BC2(1);
                    end
                elseif(p == nx*ny)
                    if isnan(BC2(3))

                        else
                            B2(p)=BC2(3);
                        end
                    elseif(mod(p,nx)==0)
                        if isnan(BC2(3))

                            else
                                B2(p)=BC2(3);
                            end
                        end
                    end
                end
            end
        end
    end
end
```

```
        end
    elseif(mod(p-1,nx)==0)
        if isnan(BC2(1))

            else
                B2(p) = BC2(1);
            end
        elseif(1<p&p<nx)
            if isnan(BC2(4))

                else
                    B2(p) =BC2(4);
                end
            elseif((1+(ny-1)*nx)<p&p<nx*ny)
                if isnan(BC2(2))

                    else
                        B2(p) =BC2(2);
                    end
                else

            end

        end

    end

for p = 1:ny2
    for m = 1:nx2
        n = m+(p-1)*nx2;
        nxm = (m-1)+(p-1)*nx2;
        nxp = (m+1)+(p-1)*nx2;
        nym = (m)+(p-2)*nx2;
        nyp = m+(p)*nx2;
        nxm2 = (m-2)+(p-1)*nx2;
        nxp2=(m+2)+(p-1)*nx2;
        nym2 = (m)+(p-3)*nx2;
        nyp2 = m+(p+1)*nx2;
        nxp3 = (m+3)+(p-1)*nx2;
        nxm3 = (m-3)+(p-1)*nx2;

        if m == 1
            G2(n,:) = 0;
            G2(n,n) = 1;

        elseif m==nx2
            G2(n,:) = 0;
            G2(n,n) = 1;

        elseif p == 1

            ryp = (cond(p,m)+cond(p+1,m))/2;
            rxp = (cond(p,m)+cond(p,m+1))/2;
            rxm = (cond(p,m)+cond(p,m-1))/2;

            G2(n,n) = -(ryp+rxp+rxm);
```



```

        G2(n, nyp) = ryp;
        G2(n, nxm) = rxm;
        G2(n, nxp) = rxp;

    elseif p == ny2
        rym = (cond(p, m) + cond(p-1, m)) / 2;
        rxp = (cond(p, m) + cond(p, m+1)) / 2;
        rxm = (cond(p, m) + cond(p, m-1)) / 2;

        G2(n, n) = -(rym + rxp + rxm);
        G2(n, nym) = rym;
        G2(n, nxm) = rxm;
        G2(n, nxp) = rxp;
    else
        ryp = (cond(p, m) + cond(p+1, m)) / 2;
        rym = (cond(p, m) + cond(p-1, m)) / 2;
        rxp = (cond(p, m) + cond(p, m+1)) / 2;
        rxm = (cond(p, m) + cond(p, m-1)) / 2;

        G2(n, n) = -(ryp + rym + rxp + rxm);
        G2(n, nyp) = ryp;
        G2(n, nym) = rym;
        G2(n, nxm) = rxm;
        G2(n, nxp) = rxp;
    end

end

end
%figure('name', 'Matrix')
%spy(G2)

V3 = G2 \ B2';
Vout2 = zeros(ny, nx);
for p = 1:ny
    for m = 1:nx
        n = m + (p-1)*nx;
        Vout2(p, m) = V3(n);
    end
end

% figure
% surf(cond)
% xlabel('X')
% ylabel('Y')
% zlabel('conductance')
% figure
% surf(Vout2)
% xlabel('X')
% ylabel('Y')
% zlabel('V')
% view(-45, -45)

Ex = size (Vout2);
Ey = size (Vout2);

```

```
for p = 1:ny
    for m = 1:nx

        if (m==1)
            Ex(p,m) = Vout2(p,m+1)-Vout2(p,m);
        elseif m == nx
            Ex(p,m) = Vout2(p,m)-Vout2(p,m-1);
        else
            Ex(p,m) = (Vout2(p,m+1)-Vout2(p,m-1))/2;

        end

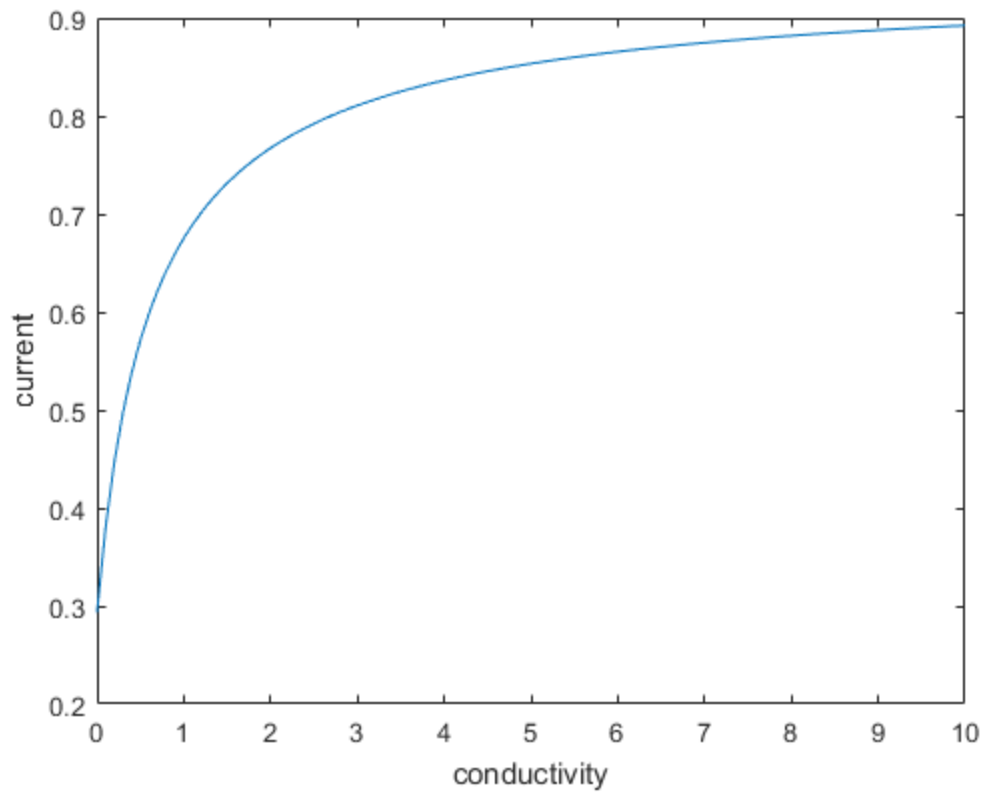
        if (p==1)
            Ey(p,m) = Vout2(p+1,m)-Vout2(p,m);
        elseif p == ny
            Ey(p,m) = Vout2(p,m)-Vout2(p-1,m);
        else
            Ey(p,m) = (Vout2(p+1,m)-Vout2(p-1,m))/2;

        end
    end
end
Ex = -Ex;
Ey = -Ey;

currentx = cond.*Ex;
currenty = cond.*Ey;

% figure
% quiver(Ex, Ey);
% xlabel('X')
% ylabel('Y')
%
%
% figure
% quiver(currentx,currenty)
% xlabel('X')
% ylabel('Y')

current(1) = mean(sum(sqrt(currentx.^2+ currenty.^2)));
end
figure
plot(t*10e-2,current)
xlabel('conductivity')
ylabel('current')
```



Conclusion

In conclusion in this assignment the current handling ability of a semiconductor was analysed using the finite difference method. The effect of mesh size, bottleneck size and conductivity were also analysed. It was found that the accuracy of the simulation is dependent on the mesh size. It was also found that increasing the size of the bottleneck decreases the current whereas an increase in their conductivity increases the current.

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